

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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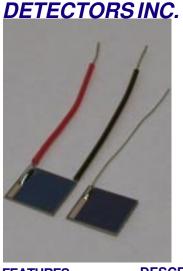


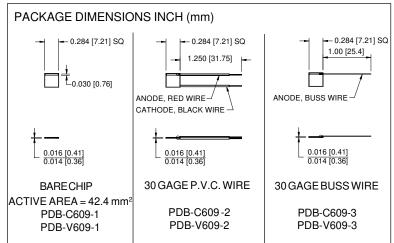




**PHOTONIC** Silicon Photodiode, Blue Enhanced Solderable Chips

Photoconductive Type PDB-C609 Photovoltaic Type PDB-V609





## **FEATURES**

- Blue enhanced
- Photovoltaic type
- Photoconductive type
- High quantum efficiency

# **DESCRIPTION:** Low cost blue enhanced planar diffused silicon solderable photodiode. The PDB-V609 cell is designed

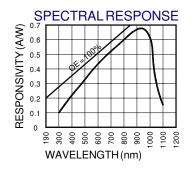
for low noise, photovoltaic applications. The PDB-C609 cell is designed for low capacitance, high speed, photoconductive operation. They are available bare, PVC or buss wire leads.

#### **APPLICATIONS**

- Optical encoder
- Position sensor
- Industrial controls
- Instrumentation

## ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	PDB-C609		PDB-V609		UNITS	
		MIN	MAX	MIN	MAX	Ortifo	
VBR	Reverse Voltage		75		25	V	
T <sub>stg</sub>	Storage Temperature	-40	+125	-40	+125	°C	
To	Operating Temperature Range	-40	+100	-40	+100	°C	
Ts	Soldering Temperature		+224		+224	∘C	
I <sub>1</sub>	Light Current		500		500	mA	



### ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TESTCONDITIONS	PDB-C609			PDB-V609			LINITO
			MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Isc	Short Circuit Current	H = 100 fc, 2850 K	490	545		490	545		$\mu$ A
ΙD	Dark Current	H = 0, V <sub>R</sub> = 5 V*		30	75		50	100	nA
Rsh	Shunt Resistance	H = 0, V <sub>R</sub> = 10 mV	3	10		5	15		$M\Omega$
TC Rsh	RsH Temp. Coefficient	H = 0, V <sub>R</sub> = 10 mV		-8			-8		%/°C
C₁	Junction Capacitance	H = 0, V <sub>R</sub> = 5 V**		240			5500		рF
λrange	Spectral Application Range	Spot Scan	350		1100	350		1100	nm
λр	Spectral Response - Peak	Spot Scan		940			940		nm
VBR	Breakdown Voltage	I = 10 μA	25	50		5	15		V
NEP	Noise Equivalent Power	V <sub>R</sub> = 0 V @ Peak	4 x 10 <sup>-13</sup> TYP		1.2 x 10 <sup>-13</sup> TYP			W/ √Hz	
tr	Response Time	$RL = 1 \ K\Omega \ V_R = 5 \ V^{**}$		30			1500		nS

<sup>\*\*</sup>VR = 0 V on Photovoltaic type \*VR = 100 mV on Photovoltaic type